

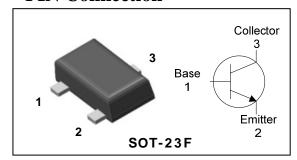
DN050S

NPN Silicon Transistor

Features

- Extremely low collector-to-emitter saturation voltage (V_{CE(SAT)}= 0.07V Typ. @I_C/I_B= 100mA/10mA)
- Suitable for low voltage large current drivers
- Complementary pair with DP050S
- Switching Application.

PIN Connection



Ordering Information

Type NO.	Marking	Package Code
DN050S	N02 ☐ ① ②	SOT-23F

¹ Device Code 2 Year&Week Code

Absolute maximum ratings

(Ta=25°C)

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V_{CBO}	15	V
Collector-Emitter voltage	V_{CEO}	12	V
Emitter-Base voltage	V_{EBO}	5	V
Collector current	Ic	500	m A
Collector dissipation	P _C	200	m W
Junction temperature	T_{j}	150	°C
Storage temperature	T_{stg}	-55~ 150	°C

Electrical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV _{CBO}	$I_{C} = 50 \mu A, I_{E} = 0$	15	-	-	V
Collector-Emitter breakdown voltage	BV _{CEO}	$I_{C}=1 \text{ m A}, I_{B}=0$	12	-	-	V
Emitter-Base breakdown voltage	BV _{EBO}	$I_E = 50 \mu A, I_C = 0$	5	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 12V, I _E = 0	-	-	0.1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0	-	-	0.1	μА
DO compant main	h _{FE1}	V _{CE} = 1V, I _C = 100mA	200	-	450	-
DC current gain	h _{FE2}	V _{CE} = 1V, I _C = 500m A	70	-	-	-
Collector-Emitter saturation voltage	$V_{CE(sat)}$	I _C = 100mA, I _B = 10mA	-	-	0.25	V
Base-Emitter saturation voltage	$V_{BE(sat)}$	I _C = 100mA, I _B = 10mA	-	-	1.2	V
Transition frequency	f _T	$V_{CE} = 5V, I_{C} = 20 \text{ m A}$	-	120	-	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10V, I _E = 0, f= 1MHz	-	4.5	-	pF

KSD-T5C073-000

2

Electrical Characteristic Curves

Fig. 1 P_C - T_a

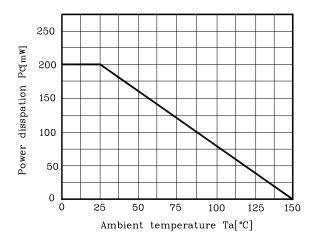


Fig. 3 $h_{FE}\ -\ I_{C}$

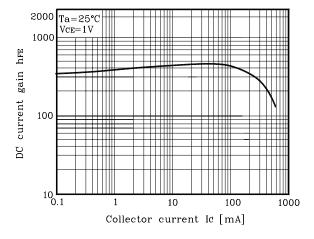


Fig. 5 $V_{CE(sat)}$ - I_C

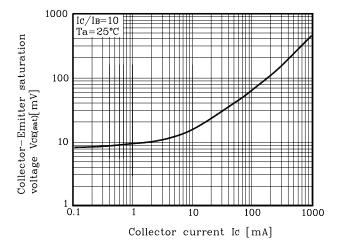


Fig. 2 $I_{C}\,$ - $\,V_{BE}\,$

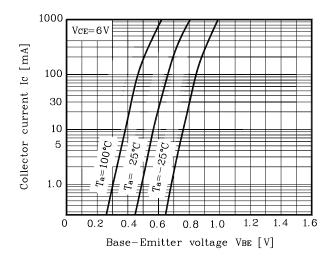
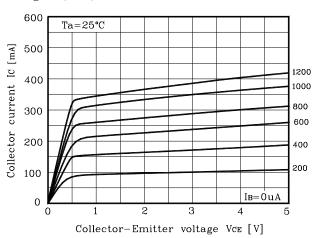
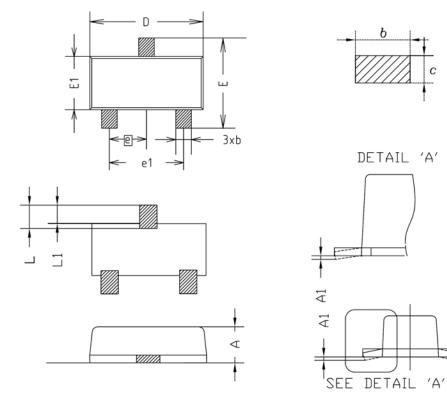
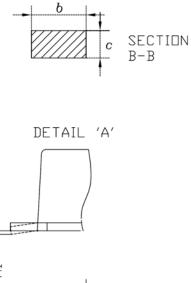


Fig. 4 I_C - V_{CE}



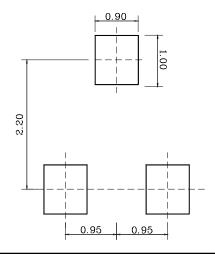
Outline Dimension





SYMBOL	MILLIMETER(mm)			NOTE	
STADUL	MINIMUM	NDMINAL	MAXIMUM	NUIE	
Α	0.80	0.90	1.00		
A1	0.00	-	0.10		
b	0.35	0.40	0.45		
C	0.10	0.15	0.20		
D	2.80	2.90	3.00		
Ε	2.30	2.40	2.50		
E1	1.50	1.60	1.70		
е	0.95BSC				
e1	1.80	1.90	2.00		
L	0.48	0.58	0.68		
L1	0.30	-	0.50		

*Recommend PCB solder land [Unit: mm]



The AUK Corp. products are intended for the use as components in general electronic equipment (Office and communication equipment, measuring equipment, home appliance, etc.).

Please make sure that you consult with us before you use these AUK Corp. products in equipments which require high quality and / or reliability, and in equipments which could have major impact to the welfare of human life(atomic energy control, airplane, spaceship, transportation, combustion control, all types of safety device, etc.). AUK Corp. cannot accept liability to any damage which may occur in case these AUK Corp. products were used in the mentioned equipments without prior consultation with AUK Corp..

Specifications mentioned in this publication are subject to change without notice.

KSD-T5C073-000